

View Online at <https://aerobasegroup.com/nsn/5961-01-355-7547>

Inclosure Material:

Metal

Overall Length:

Between 0.165 inches and 0.185 inches

Terminal Length:

Between 0.500 inches and 0.560 inches

Overall Diameter:

Between 0.340 inches and 0.370 inches

Component Name And Quantity:

2 transistor

Mounting Method:

Terminal

Terminal Circle Diameter:

0.200 inches

Features Provided:

Burn in

Semiconductor Material:

Silicon all transistor

Voltage Rating In Volts Per Characteristic:

10.0 collector to base voltage, dc all transistor and 5.0 emitter to base, rms all transistor

Current Rating Per Characteristic:

50.00 milliamperes source cutoff current all transistor

Power Rating Per Characteristic:

200.0 milliwatts small-signal input power, common-collector preset all transistor

Maximum Operating Temperature Per Measurement Point:

175.0 degrees celsius junction

Special Features:

All transistor junction pattern arrangement: npn

Terminal Type And Quantity:

8 uninsulated wire lead

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

No

Fiig:

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